

MOSFETs Silicon N-Channel MOS (DTMOSVI)

# TK063Z60Z1

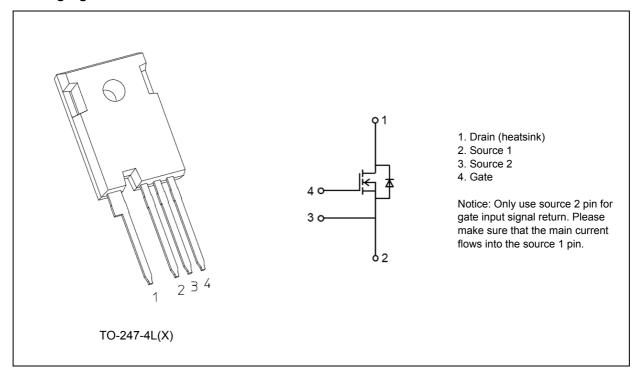
#### 1. Applications

· Switching Power Supplies

#### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.053 \Omega$  (typ.)
- (2) High-speed switching properties with the lower capacitance.
- (3) Enhancement mode:  $V_{th}$  = 3 to 4 V ( $V_{DS}$  = 10 V,  $I_{D}$  = 1.47 mA)

#### 3. Packaging and Internal Circuit



Start of commercial production

1



# 4. Absolute Maximum Ratings (Note) (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	600	V
Gate-source voltage	,	$V_{GSS}$	±30	
Drain current (DC)	(Note 1)	I <sub>D</sub>	37	Α
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	148	
Power dissipation (7	Γ <sub>c</sub> = 25 °C)	$P_{D}$	242	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	609	mJ
Single-pulse avalanche current		I <sub>AS</sub>	6.1	Α
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	37	
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	148	
Channel temperature		T <sub>ch</sub>	150	ů
Storage temperature		T <sub>stg</sub>	-55 to 150	
Mounting torque		TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	0.515	°C/W
Channel-to-ambient thermal resistance	R <sub>th(ch-a)</sub>	50	

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25 °C (initial), L = 29 mH,  $I_{AS}$  = 6.1 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

2024-12-24



#### 6. Electrical Characteristics

#### 6.1. Static Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μА
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V	_	_	2	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	600	_	_	V
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.47 mA	3	_	4	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 12.8 A	_	0.053	0.063	Ω

### 6.2. Dynamic Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance		C <sub>iss</sub>	$V_{DS} = 300 \text{ V}, V_{GS} = 0 \text{ V}, f = 100 \text{ kHz}$	_	3200	_	pF
Reverse transfer capacitance		C <sub>rss</sub>		_	3	_	
Output capacitance		C <sub>oss</sub>		_	77	_	
Effective output capacitance (energy related)	(Note 3)	C <sub>o(er)</sub>	V <sub>DS</sub> = 0 to 400 V, V <sub>GS</sub> = 0 V		128		
Effective output capacitance (time related)	(Note 4)	C <sub>o(tr)</sub>	V <sub>DS</sub> = 0 to 400 V, V <sub>GS</sub> = 0 V	-	910		
Gate resistance		r <sub>g</sub>	V <sub>DS</sub> = OPEN , f = 1 MHz	_	2.5	_	Ω
Switching time (rise time)		t <sub>r</sub>	See Fig. 6.2.1	_	22	_	ns
Switching time (turn-on time)		t <sub>on</sub>		_	55	_	
Switching time (fall time)		t <sub>f</sub>		_	5	_	
Switching time (turn-off time)		t <sub>off</sub>		_	105		
MOSFET dv/dt ruggedness		dv/dt	$V_{DS} \le V_{DSS}, I_D \le 18.5 A$	120	_		V/ns

Note 3:  $C_{O(er)}$  is a fixed capacitance that gives the same stored energy as  $C_{OSS}$  while  $V_{DS}$  is rising from 0 V to 400 V. Note 4:  $C_{O(tr)}$  is a fixed capacitance that gives the same charging time as  $C_{OSS}$  while  $V_{DS}$  is rising from 0 V to 400 V.

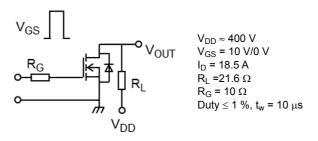


Fig. 6.2.1 Switching Time Test Circuit

#### 6.3. Gate Charge Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 37 \text{ A}$	1	56	I	nC
Gate-source charge 1	Q <sub>gs1</sub>		_	18		
Gate-drain charge	$Q_{gd}$		_	15	_	



# 6.4. Source-Drain Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	$V_{DSF}$	I <sub>DR</sub> = 37 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time		V <sub>DD</sub> = 400 V,	_	350	_	ns
Reverse recovery charge	$Q_{rr}$	$I_{DR}$ = 18.5 A, $V_{GS}$ = 0 V -d $I_{DR}$ /dt = 100 A/ $\mu$ s	_	5.3	_	μС
Peak reverse recovery current	I <sub>rr</sub>	-αιρκ/αι – 100 Α/μ3		30	_	Α
Diode dv/dt ruggedness	dv/dt	$V_{DD} \le 400 \text{ V}, I_{DR} \le 18.5 \text{ A}, V_{GS} = 0 \text{ V}$	40		_	V/ns

## 7. Marking (Note)

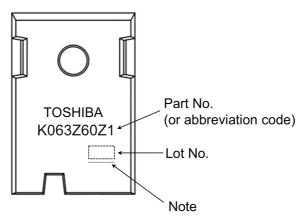


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Rev.1.0



#### 8. Characteristics Curves (Note)

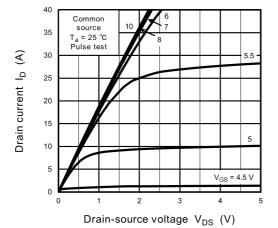


Fig. 8.1 I<sub>D</sub> - V<sub>DS</sub>

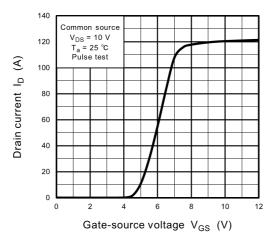


Fig. 8.3 I<sub>D</sub> - V<sub>GS</sub>

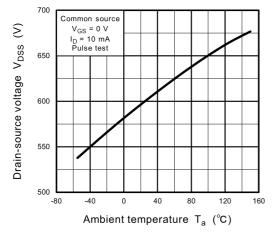


Fig. 8.5 V<sub>DSS</sub> - T<sub>a</sub>

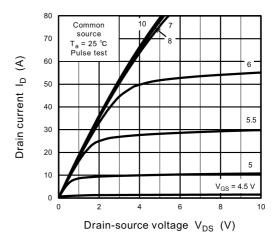


Fig. 8.2 I<sub>D</sub> - V<sub>DS</sub>

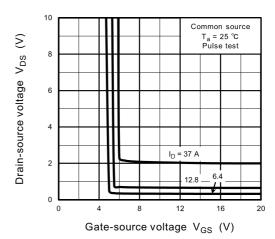


Fig. 8.4 V<sub>DS</sub> - V<sub>GS</sub>

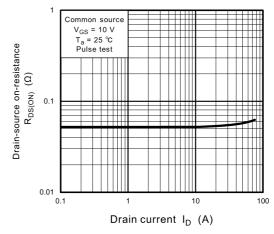
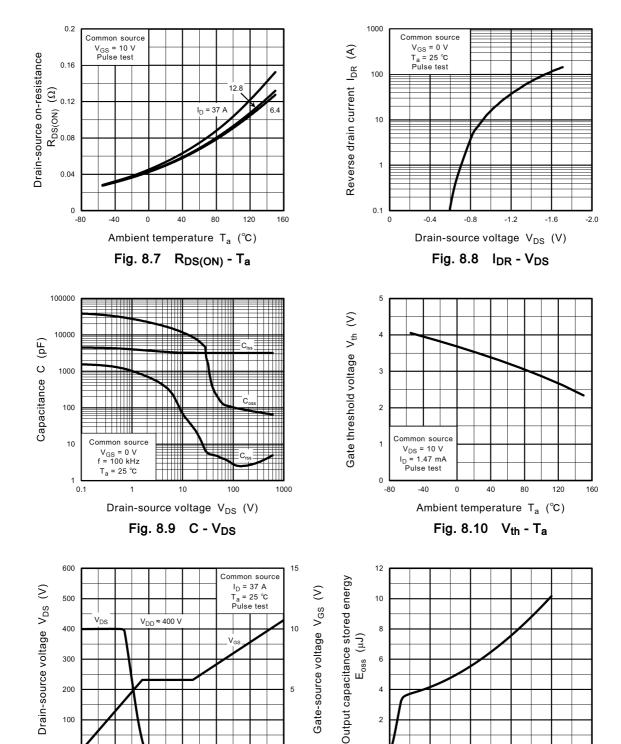


Fig. 8.6 R<sub>DS(ON)</sub> - I<sub>D</sub>





Total gate charge  $Q_q$  (nC) **Dynamic Input/Output Characteristics** 

30

20

Drain-source voltage  $V_{DS}$  (V) Fig. 8.12 Eoss - V<sub>DS</sub>

200

100

0

0

60

0



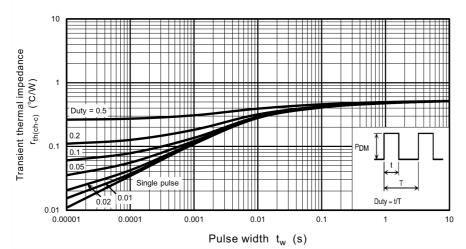


Fig. 8.13 r<sub>th</sub> - t<sub>w</sub> (Guaranteed Maximum)

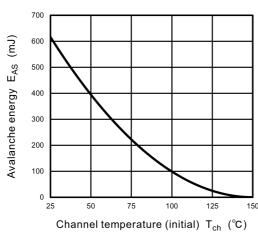


Fig. 8.14 E<sub>AS</sub> - T<sub>ch</sub> (Guaranteed Maximum)

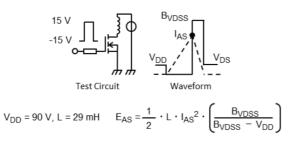


Fig. 8.16 Test Circuit/Waveform

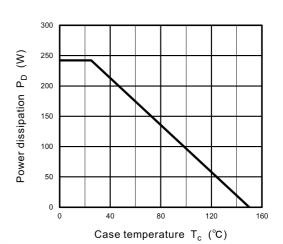


Fig. 8.15 P<sub>D</sub> - T<sub>c</sub> (Guaranteed Maximum)

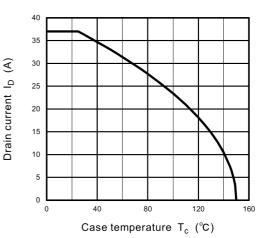


Fig. 8.17 I<sub>D</sub> - T<sub>c</sub> (Guaranteed Maximum)



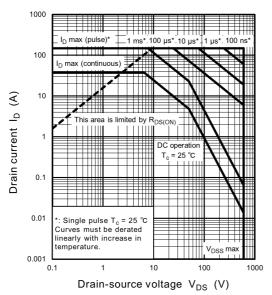


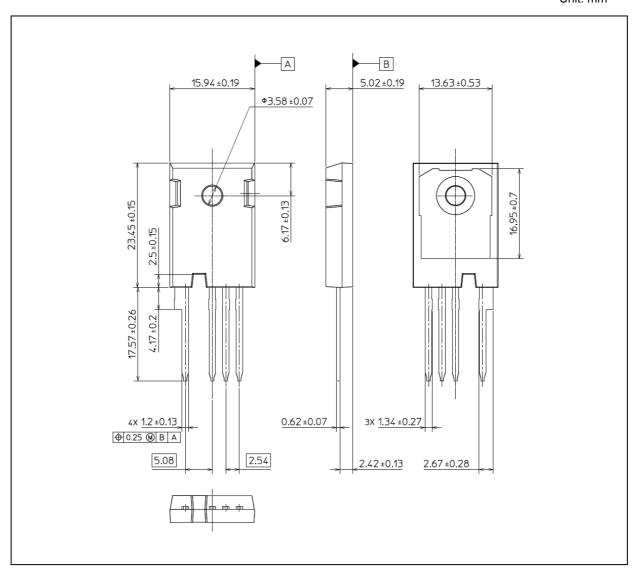
Fig. 8.18 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



# **Package Dimensions**

Unit: mm



Weight: 6.55 g (typ.)

Package Name(s)
TOSHIBA: 2-16M3A
Nickname: TO-247-4L(X)



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